### Quantum di usion of dipole-oriented indirect excitons in coupled quantum wells

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(M ay 06, 2002)

A model for di usion of statistically-degenerate excitons in (coupled) quantum wells is proposed and analysed. W ithin a microscopic approach, we derive a quantum di usion equation, calculate and estim ate the self-di usion coe cient for excitons in quantum wells and derive a modi ed E instein relation adapted to statistically-degenerated quasi-two-dimensional bosons. It is also shown that the dipole-dipole interaction of indirect excitons e ectively screens long-range-correlated disorder in quantum wells. Numerical calculations are given for indirect excitons in G aA s/A IG aA s coupled quantum wells.

71.35.-y, 73.63 H s

#### I. IN TRODUCTION

A system of indirect excitons in G aA s/A IG aA scoupled quantum wells (QW s) is a unique object for studing the transport and collective properties of interacting quasitwo-dimensional (quasi-2D) composite bosons. This is due to (i) a well-de ned dipole-dipole repulsive interaction between indirect excitons, which is not sensitive to the internal spin structure of the particles (the exchange interaction is extrem ely weak so that the degeneracy factor g = 4), (ii) the absence of quasi-2D excitonic m olecules, (iii) strong suppression of the interface polariton e ect and a long radiative livetim e of excitons, and, as we show below, (iv) e ective screening of in-plane QW disorder by interacting indirect excitons.

The indirect excitons in coupled G aA s/A IG aA s have been extensively studied in various optical experiments (see, e.g., [1{6]}. In particular, a specic jump of the signal intensity in photolum inescence (PL) dynam – ics of indirect excitons and its nonlinear behaviour have been interpreted in terms of Bose-E instein (BE) stim ulated scattering of statistically-degenerate Bose-particles [2]. Furtherm ore, very recently a substantial progress has been achived in spatial con nement of quantum – degenerate indirect excitons by using a dip potential trap naturally-grown in G aA s/A IG aA s coupled QW s  $\beta$ ]. A theory of the acoustic-phonon-assisted relaxation kinetics of statistically-degenerate QW excitons has been developed in [7{9].

For a dilute (quasi-) equilibrium gas of indirect excitons the degeneracy temperature  $T_0$  and the chemical potential are given by

$$T_0 = \frac{h^2}{2} \frac{h^2}{M_x} n_{2d}$$
 and  $= k_B T \ln 1 e^{T_0 = T}$ ; (1)

where M  $_x$ ,  $n_{2d}$  and T are the in-plane translationalm ass, concentration and tem perature of excitons, respectively. C rossover from classical to quantum, BE statistics occurs at T  $T_0$ . The aim of the work is to develop a theoretical

m odel for di usive in-plane propagation of statisticallydegenerate QW excitons.

# II.OUTLINE OF THE QUANTUM DIFFUSION THEORY

We assume that exciton-exciton interaction is dominant  $(n_{2d} 10^9 \text{ cm}^2, \text{according to the estimate given in [7]})$  so that a system of quasi-2D excitons can be described in terms of the local quasi-equilibrium (thermodynamic) states. The self-di usion ux density of QW excitons,  $J_x^{\rm di}$ , is given by

$$J_{x}^{di} = D_{x}^{(2d)} r n_{2d} \frac{D_{T}^{(2d)}}{T} r T ; \text{ where}$$

$$D_{T}^{(2d)} = \frac{T}{2} n_{2d} l_{2d} \frac{\theta v_{2d}}{\theta T} n_{2d} v_{2d} \frac{\theta l_{2d}}{\theta T} \text{ and}$$

$$D_{x}^{(2d)} = \frac{1}{2} n_{2d} l_{2d} \frac{\theta v_{2d}}{\theta n_{2d}} + l_{2d} v_{2d} n_{2d} v_{2d} \frac{\theta l_{2d}}{\theta n_{2d}} : (2)$$

Here,  $D_x^{(2d)}$  and  $D_T^{(2d)}$  are the di usion and therm ald iffusion coe cients, respectively,  $l_{2d}$  is the mean free path of excitons and  $v_{2d}$  is their average therm alvelocity.

The mean free path of QW excitons is determined by  $l_{2d} = v_{2d} \begin{pmatrix} 2d \\ x & x \end{pmatrix}$ , where  $\begin{pmatrix} 2d \\ x & x \end{pmatrix}$  is a characteristic scattering time due to exciton-exciton interaction. Thus one derives

$$l_{2d} = v_{2d} \frac{2 C h^3}{j u_0 f n_{2d} M_x};$$
(3)

where C is a num erical constant of the order of unity,  $u_0=S$  is the potential of exciton-exciton interaction and S is the QW area.

For small transferred m om enta in exciton-exciton scattering,  $u_0$  is given by

$$u_0 = \frac{h^2}{x (d)}; \qquad (4)$$

where  $_{\rm x}$  is the reduced exciton m ass and d is the e ective separation between the electron and hole layers. The

dimensionless function (d) has two well-de ned limits, at d  $a_{2d}^{B}$  and d  $a_{2d}^{B}$   $[a_{2d}^{B} = (h^{2} "_{b})=(2_{x})$  is the 2D exciton B ohr radius and "<sub>b</sub> is the dielectric constant]. The rst limit corresponds to the exciton-exciton exchange interaction in single QW s. In this case (d = 0) is very close to unity [7], i.e., (0) = 1.036, according to rstprinciple calculations [10]. The second limit deals with a well-de ned dipole-dipole interaction of indirect excitons in coupled QW s. In this case (d  $a_{2d}^{B}) = a_{2d}^{B} = (2d)$ and Eq. (4) reduces to  $u_{0} = 4$  ( $e^{2}$ ="<sub>b</sub>)d. The latter is consistent with the plate capacitor formula. Thus we approximate

(d) = 
$$\begin{array}{ccc} 1; & d & a_{2d}^{B} \\ a_{2d}^{B} = (2d); & d & a_{2d}^{B}: \end{array}$$
 (5)

U sing Eqs. (3)-(4) one gets from Eq. (2):

$$D_{x}^{(2d)} = D_{x}^{(2d)} (T;T_{0}) = C \frac{h}{M_{x}}^{2} (d) \frac{x}{M_{x}}^{2}$$
$$\frac{1}{2k_{B}} \frac{\partial E_{kin}}{\partial T_{0}} + 2 \frac{E_{kin}}{k_{B}T_{0}} ; \qquad (6)$$

where the average therm alrenergy of QW  $\,$  excitons is given by

$$E_{kin} = k_{B} \frac{T^{2}}{T_{0}} \frac{Z_{1}}{0} \frac{zdz}{exp[ = k_{B}T) + z] - 1}$$
(7)

with and  $T_0$  defined by Eq.(1). In Fig.1 we plot  $D_x^{(2d)} = D_x^{(2d)}$  (T;T<sub>0</sub>) calculated for various T and  $T_0$  (note that  $T_0$  is proportional to  $n_{2d}$ ) by using Eqs.(6)-(7) with  $= a_{2d}^B = (2d)$  and C = 4 = . In the limit of classical, M axwell-Boltzm ann statistics of QW excitons, when T  $T_0$ , Eqs.(6)-(7) reduce to

$$D_{x}^{(2d;cl)} = 2C \frac{h}{M_{x}}^{2} (d) \frac{x}{M_{x}}^{2} \frac{T}{T_{0}} :$$
 (8)

Note that for a classical 3D gas of excitons one has  $D_x^{(3d)} / T^{1=2}$ . In the lim it of well-developed quantum statistics, T  $T_0$ , Eqs.(6)-(7) yield

$$D_{x}^{(2d,qm)} = \frac{2}{4}C\frac{h}{M_{x}}^{2} (d) \frac{x}{M_{x}}^{2} \frac{T}{T_{0}}^{2} : \qquad (9)$$

D rastic reduction of D  $_x^{(2d;qm)}$  in comparison with D  $_x^{(2d;cl)}$  is due to non-classical accumulation of low-energy QW excitons which occurs at T < T<sub>0</sub>.

Substitution of Eq.(3) into the expression for  $D_T^{(2d)}$ [see Eq.(2)] yields  $D_T^{(2d)} = 0$ , because  $l_{2d}$  ( $v_{2d}=0T$ ) =  $v_{2d}$  ( $l_{2d}=0T$ ). This is in a sharp contrast with the 3D case, when ( $l_{3d}=0T$ ) ' 0 and  $v_{3d}=0T$  / T  $^{1=2}$  give rise to the therm aldi usion coe cient  $D_T^{(3d)}$  / T  $^{1=2}$  for M axwell-Boltzm ann statistics. Thus self-therm odi usion of QW excitons is negligible in comparison with self-di usion which is due to the concentration gradient. The drift ux density of QW excitons,  $J_x^{\rm drift}$  , is given by

$$J_x^{driff} = {}^{(2d)} n_{2d} r (u_0 n_{2d} + U_{QW}); \qquad (10)$$

where <sup>(2d)</sup> is the mobility of quasi-2D excitons and  $U_{QW}$  is the in-plane QW potential. The rst term in the square brackets on the right hand side of Eq. (10) describes the drift ux due to repulsive exciton-exciton interaction. The exciton mobility is determined through  $D_x^{(2d)}$  by

$${}^{(2d)} = \frac{D_{x}^{(2d)} h}{k_{\rm B} T_{0}} e^{T_{0} = T} \qquad 1 : \qquad (11)$$

For T  $T_0$  Eq.(11) reduces to the Einstein relation, i.e.,  $^{(2d)} = D_x^{(2d)} = (k_B T)$ . In the quantum limit T  $T_0$ , how ever, Eq.(11) gives strong  $n_{2d}$ -dependent increase of the exciton mobility calculated in terms of  $D_x^{(2d)}$ .

By using Eqs.(2), (10) and (11), we end up with the nonlinear quantum di usion equation:

$$\frac{@n_{2d}}{@t} = r D_{x}^{(2d)} r n_{2d} + \frac{2}{r} \frac{M_{x}}{h^{2}} D_{x}^{(2d)} e^{T_{0}=T} 1$$

$$r (u_{0}n_{2d} + U_{QW}) \frac{n_{2d}}{opt} + ; \quad (12)$$

where the optical lifetime  $_{opt} = _{opt} (T;T_0) of QW$  excitons is given by Eqs. (32)-(35) of [7], the self-di usion coe cient D  $_x^{(2d)} = D_x^{(2d)} (T;T_0)$  is determined by Eqs. (6)-(7) and =  $(r_k;t)$  is the generation rate of excitons. Note that the numerical constant C ' 1 in the expression (6) for D  $_x^{(2d)}$  can be calculated by analysing the relevant linearized quantum kinetic equation with standard methods [11,12] developed for classical bulk gases.

## III.SCREEN IN G OF LONG-RANGE-CORRELATED DISORDER

One of the most interesting results of the di usion Eq.(12) is elective screening of long-range-correlated QW disorder by dipole-dipole interaction of indirect excitons. In sharp contrast with excitons in single QW s, the blue-shift of the indirect exciton line, which has already been observed in many experiments (see, e.g., [1,5]), accurately to the mean-eld-theory result,  $U = u_0 n_{2d}$ , over a broad range of concentrations,  $10^8 \text{ cm}^{-2} - n_{2d}$  $10^{11} \text{ cm}^{-2}$ . Here  $u_0$  is given by Eq. (4) with (d) =  $a_{2d}^B = (2d)$ .

In order to demonstrate and estim ate analytically the screening e ect, we put  $1 = _{opt} = 0$  (no optical decay) and = 0 (no source of indirect excitons). In this case a steady-state solution of Eq.(12) can be found analytically. The input, unscreened in-plane random potential  $U_{QW} = U_{rand} (r_k)$  is due to the QW thickness and alloy uctuations,  $r_k$  is the in-plane coordinate. For average concentrations of indirect QW excitons such that  $u_0 n_{2d}^{(0)} = J_{rand} (r_k)$  j the steady-state solution yields

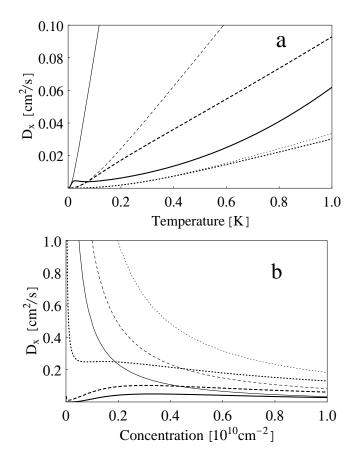


FIG. 1. Diusion coe cient of indirect excitons in GaAs/AlGaAs coupled QW s calculated using Eqs.(6)-(7) with C = 4= and =  $a_{2d}^{B}$ =(2d). (a) The diusion coe - cient versus T for  $n_{2d}$  = 10<sup>9</sup> cm<sup>-2</sup> (solid lines), 5 10<sup>9</sup> cm<sup>-2</sup> (dashed lines) and 2 10<sup>10</sup> cm<sup>-2</sup> (dotted lines). (b) The diusion coe cient against n <sub>2d</sub> for T = 0.5K (solid lines), 1K (dashed lines) and 2K (dotted lines). D<sub>x</sub><sup>(2d)</sup> and D<sub>x</sub><sup>(2d)</sup> are shown by the thin and bold lines, respectively. M<sub>x</sub> = 0.215m<sub>0</sub>, <sub>x</sub> = 0.046m<sub>0</sub> and d = 11.5nm.

$$n_{2d} = \frac{U_{rand} (r_k) n_{2d}^{(0)}}{k_B T_0 (e^{T_0 = T} 1)^{1} + u_0 n_{2d}^{(0)}};$$
  

$$U_e = u_0 n_{2d}^{(0)} + \frac{U_{rand} (r_k)}{1 + [(2M_x) = (h^2)] (e^{T_0 = T} 1) u_0};$$
 (13)

where  $n_{2d} = n_{2d} (r_k)$   $n_{2d}^{(0)} \cdot U_e = U_{rand} (r_k) + u_0 n_{2d} (r_k)$ is the elective, screened in-plane potential. Relaxation of the long-range-correlated random potential is described by the denom inator in the expression for  $U_e$  [see Eq.(13)]. For  $n_{2d}^{(0)}$   $y_{rand}=u_0$  j the denom inator is much larger than unity. For classical statistics, when T  $T_0$ , relationships (13) reduce to  $n_{2d} (r_k) = [U_{rand} (r_k) n_{2d}^{(0)}] = k_B T + u_0 n_{2d}^{(0)}]$  and  $U_e (r_k) = u_0 n_{2d}^{(0)} + [U_{rand} (r_k) k_B T] = k_B T + u_0 n_{2d}^{(0)}]$ . For  $u_0 n_{2d}^{(0)}$   $k_B T$  the

 $U_{rand}(\mathbf{r}_k) \mathbf{k}_B T = \mathbf{k}_B T + u_0 \mathbf{n}_{2d}$  J. For  $u_0 \mathbf{n}_{2d}$   $\mathbf{k}_B T$  the latter expression describes strong suppression of the potential uctuations, i.e., instead of input  $U_{rand}(\mathbf{r}_k)$  one gets  $U_{rand}(\mathbf{r}_k)$  with  $= (\mathbf{k}_B T) = (u_0 \mathbf{n}_{2d}^{(0)})$  1. The screening e ect become sparticularly strong in the quantum regime,  $T_0$  T. Form ally this is due to the term [exp( $T_0=T$ ) 1] in the expressions (13).

In Fig.2 we plot the elective potential U  $_{\rm e}$  (x)  $u_0 n_{2d}^{(0)}$ and concentration of excitons,  $n_{2d}(x)$ , calculated with Eq.(12) for a model 1D long-range-correlated random potential U<sub>rand</sub> (x), shown by the bold lines, and realistic values of  $n_{\rm 2d}^{\,(0)}$  , D  $_{\rm x}$  , T ,  $_{\rm opt}$  and am plitude of U  $_{\rm rand}$ (about 0:5m eV). Figure 2 clearly illustrates the origin of the screening e ect: A coumulation of indirect excitons in the minima of  $U_{rand}(r_k)$  and their depletion at the maxim a of  $U_{rand}(r_k)$ . In the experiments [1{3] the blueshift of the energy of indirect excitons  $U = u_0 n_{2d}^{(0)}$ 1:6 m eV for  $n_{2d}^{(0)} = 10^{10}$  cm<sup>2</sup>. For this moderate 1:4 concentration of excitons the long-range-correlated inplane disorder is already drastically screened and relaxed at T 42K (see also Fig.2). One can directly include the disorder-assisted e ects into di usion Eq. (12) by using a therm ionic model. In this case we replace D  $_{\rm x}^{\rm (2d)}$  by  $\widetilde{D}_{x}^{(2d)} = D_{x}^{(2d)} \exp (\frac{1}{2})$  $u_0 n_{2d}^{(0)}$ )=(k<sub>B</sub>T) and remove (U<sub>e</sub>  $U_{QW} = U_{rand}$  from eq. (12). For T  $T_0$  the diusion coe cient  $D_{x}^{(2d)}$  is

$$D_{x}^{(2d;cl)} = D_{x}^{(2d;cl)} \exp \frac{U_{rand}(r_{k})}{k_{B}T + u_{0}n_{2d}^{(0)}};$$
(14)

where  $D_x^{(2d;cl)}$  is given by Eq. (8) and  $U_{rand}(r_k)$  can be replaced by  $U_{rand}^{(0)} = 2 < j U_{rand}(r_k) j >$ . The calculated di usion coe cent  $D_x^{(2d)}$ , which is relevant to the analysis of the experimental data [1{3], is shown in Fig.1. Note that due to the relatively strong dipole-dipole interaction only a dip, natural or externally applied, in-plane potential  $U_{trap}$  10 m eV can spatially con ne the indirect excitons of high concentrations  $n_{2d}^{(0)}$  5  $1\theta^0$  cm<sup>2</sup> [3,4]. Q uantum di usion of indirect excitons towards a m scale trap and their real-space distribution  $n_{2d} = n_{2d} (r_k)$ in the trap can be calculated by using Eq. (12) with  $D_x^{(2d)}$ and  $U_{0W} = U_{trap} (r_k)$  [3].

#### IV . D ISC U SSIO N

In the experiments  $[1{3}]$  with G aA s/A is aA s coupled QW s the elective temperature T of indirect excitons can considerably exceed the bath, cryostat temperature T<sub>b</sub>. The excitons cool down due to interaction with bulk LA-phonons, while incoming, optically-generated high-energy excitons tend to increase T. Thus in order to adapt the quantum di usion picture to the optical experiments, Eq. (12) should be completed with Eq. (11) of [7]. The latter describes the local temperature T = T ( $r_k$ ;t) which is  $n_{2d}$ -dependent especially for well-developed BE statistics of QW excitons.

The di usion transport occurs when  $l_{2d} = a_{2d}^{(0)} = 1$  and when the exciton-exciton interaction is the dom inant scattering mechanism. The above conditions limit the

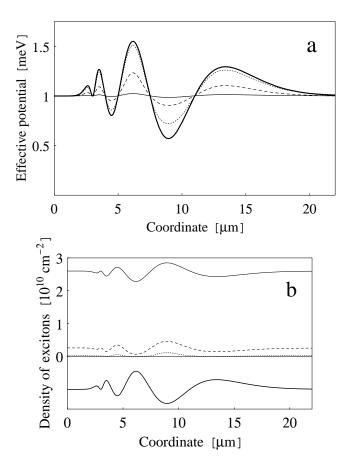


FIG. 2. Relaxation of long-range-correlated disorder by the dipole-dipole interaction of indirect excitons in G aA s/A G aA s coupled QW s. (a) The elective, screened potential  $U_e(x) = u_0 n_{2d}^{(0)}$  and (b) local concentrations of indirect excitons  $n_{2d}(x)$  versus in-plane coordinate x. The average concentrations are  $n_{2d}^{(0)} = 2.6 \quad 10^{10}$  cm<sup>-2</sup> (thin solid line), 2:6  $10^9$  cm<sup>-2</sup> (dashed line), and 2:6  $10^8$  cm<sup>-2</sup> (dotted line). Tem perature T = 2K, di usion coe cient D  $_x = 100$  cm<sup>-2</sup>/s, and radiative lifetim e  $_{opt} = 20$  ns. In both gures the input, unscreened potential  $U_{rand}(x)$  is shown by bold solid lines.

application of the theory to  $10^9$  cm  $^2$   $\ensuremath{n_{2d}}\xspace 2$   $10^{10}$  cm  $^2$  for G aA s-based QW s. The developed model is de nitely not applicable for T  $\ensuremath{T_c}$ , where  $\ensuremath{T_c}$  is the transition tem perature to a super uid phase. Note that for a very dilute gas of quasi-2D excitons  $\ensuremath{T_c}\xspace$  To [13,14]. Furtherm ore, in experiments with spatially-inhom ogeneous optical generation of QW excitons the di usive propagation always precedes a possible transition to the super uid motion of excitons.

By analysing a relevant G ross-P itaevskii equation we have also found the screening e ect for mid-range-correlated (length scale of a few  $a_{2d}^B$ ) in-plane disorder. Namely the dipole-dipole interaction between excitons considerably decreases the localization energy of an indirect exciton in a mesoscopic in-plane trap. This leads to relaxation of the mid-range-correlated QW potential uctuations. Short-range 2D disorder, which can be described in terms of a random contact potential, is also

strongly suppressed by interacting bosons [15]. Thus we conclude that in high-quality G aA s/A G aA s coupled QW s the in-plane random potential of any correlation length is e ectively screened and practically removed at  $n_{2d}^{(0)} = 10^{40}$  cm<sup>-2</sup>, due to the dipole-dipole interaction of indirect excitons. In this case the in-plane momentum of indirect excitons,  $p_k$ , becomes a good quantum number even for low-energy particles, as was demonstrated in the experiments [2,16]. Thus the phonon-assisted relaxation and PL kinetics [7[9], form ulated in terms of well-de ned  $p_k$ , are adequate for explanation and m odelling of the recent experiments on statistically-degenerate excitons in G aA s/A G aA s coupled QW s [2].

W e attribute a relatively large width 0:5 1meV of the PL line associated with indirect excitons at  $n_{\rm 2d}^{(0)}$  $10^{10}$  cm  $^2$  to intrinsic, hom ogeneous broadening rather than to a disorder-assisted inhom ogeneous width. W hile the dipole-dipole interaction of indirect excitons is much weaker and of shorter-range than the  $1=r_k$  C oulom b law, it gives rise to a relatively large correlation energy in com parison with the leading m ean-eld-theory correction  $U = u_0 n_{2d}^{(0)}$ . This is because screening of the dipoledipole interaction by indirect excitons is very weak. In this case the optical decay of an indirect exciton interacting with its nearest neighbouring exciton (s) gets an energy uncertainty. The latter depends upon the distance between the interacting particles and results in a large  $(1 \text{ m eV}) \text{ T-and } n_{2d}$ -dependent hom ogeneous width of indirect excitons in G aA s/A IG aA s coupled QW s.

#### V.CONCLUSIONS

In this work we have developed a quantum di usion theory for (indirect) excitons in (coupled) quantum wells. The main results are (i) the quantum di usion Eq. (12) with the di usion coe cient, which is calculated within a microscopic picture and is given by Eqs. (6)–(7) and (14), (ii) the modi ed Einstein relation (11) between the mobility and di usion coe cient of QW excitons, and (iii) e ective screening of QW disorder by dipole-dipole interacting indirect excitons.

# ACKNOW LEDGMENTS

The author appreciates valuable discussions with L.V. Butov, D.S.Chem la and L.V.Keldysh. Support of this work by the EPSRC is gratefully acknow ledged.

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